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DK/EP 2451069 T3

DESCRIPTION

FIELD OF THE INVENTION

[0001] The invention relates to a switching branch for a three-level rectifier and a method for controlling a switching branch for a three-level rectifier.

BACKGROUND OF THE INVENTION

[0002] Three-level rectifiers are rectifiers that have three DC outputs. In addition to the positive and negative DC outputs they have a neutral DC output. Examples of three-level rectifiers are given in J. W. Kolar and F. C. Zach, "A novel three-phase utility interface minimizing line current harmonics of high-power telecommunications rectifier modules", IEEE transactions on industrial electronics, Vol. 44, No. 4, August 1997, and in Y. Zhao, Y. Li and T. A. Lipo, "Force commutated three level boost type rectifier", IEEE transactions on industry applications, Vol. 31, No. 1, January/February 1995.

[0003] Figure 1 shows an example of a switching branch for a three-level rectifier comprising six diodes D1 to D6 and two controllable switches S1, S2. The switches are controlled via a control arrangement 10 according to a modulation scheme used. Possible modulation methods are vector modulation and hysteresis modulation, for example. When current flows towards the rectifier from an AC input pole of the rectifier branch, the first switch S1 is modulated and the first diode D1 and the first switch S1 commutate with each other according to the modulation scheme used. In a corresponding manner, when the current flows away from the rectifier, the second switch S2 is modulated and the fourth diode D4 and the second switch S2 commutate with each other according to the modulation scheme used. A rectifier configuration may also include an AC filter (not shown in the figures), which may be e.g. of L-type or LCL-type and which is connected between the rectifier input pole(s) and corresponding poles of the supplying AC voltage source.

[0004] A problem related to the above example is an uneven distribution of voltage across components in a reverse blocking state. A reason for this may be impedance differences due to different component characteristics, component manufacturing or circuit configuration. In the example of Figure 1, when the third and fourth diodes D3 and D4 are in the reverse blocking state and if a reverse impedance of the fourth diode D4 is higher than the reverse impedance of the third diode D3, the voltage across the fourth diode D4 tends to be higher than the voltage across the third diode D3. However, the sixth diode D6 connected in parallel with the second switch S2 guarantees that the voltage across the fourth diode D4 is at most the same as the potential of the neutral DC output NP because the sixth diode D6 then connects the connection point of the third and fourth diodes D3 and D4 directly to the neutral DC output NP. On the other hand, if the reverse impedance of the third diode D3 is higher than the reverse

impedance of the fourth diode D4 and the voltage across the third diode D3 tends to be higher than the voltage across the fourth diode D4, the sixth diode D6 stays in a reverse blocking state and does not limit the voltage across the third diode D3. Therefore, in the worst case, the third diode D3 may be exposed to the total voltage Udc of the DC intermediate circuit. In a similar manner, when the first and second diodes D1 and D2 are in the reverse blocking state, the second diode D2 may be exposed to the total voltage Udc of the DC intermediate circuit. This is not desirable.

[0005] A solution to the problem described above is to connect additional resistors in parallel with the series-connected diodes D1 to D4 to balance the distribution of voltage across the diodes. However, such additional components cause additional costs and also additional losses.

BRIEF DESCRIPTION OF THE INVENTION

[0006] An object of the invention is thus to provide a method and an apparatus for implementing the method so as to solve or at least alleviate the above problem. The object of the invention is achieved by a switching branch for a three-level rectifier, a rectifier, a method, and a computer program product that are characterized by what is stated in the independent claims. Preferred embodiments of the invention are described in the dependent claims.

[0007] The invention is based on the idea of setting each controllable switch of the switching branch in a conducting state during the time when the switch is not modulating the input voltage of the switching branch. This may be accomplished by setting the first switch of the switching branch to be in a conductive state during the reverse blocking state of the first diode and the second diode, i.e. when the AC input pole of the switching branch is connected to the negative output pole, and by setting the second switch of the switching branch to be in a conductive state during the reverse blocking state of the third diode and the fourth diode, i.e. when the AC input pole of the switching branch is connected to the positive output pole. The conducting switch connects the neutral DC output potential to the connection point of the diodes in the reverse blocking state and thus the voltage stress of the diodes in the reverse blocking state is always at most about half the total voltage of the DC intermediate circuit.

[0008] An advantage of the invention is that by controlling the switches into a conductive state when they are not modulating the input voltage of the rectifier, the voltages across the diodes in the reverse blocking state can be balanced without the use of any additional components such as resistors. This results in lower power losses and overall costs.

BRIEF DESCRIPTION OF THE FIGURES

[0009] In the following, the invention will be described in more detail in connection with

preferred embodiments with reference to the accompanying drawings, in which

Figure 1 illustrates a circuit diagram of a rectifier switching branch according to an embodiment; and

Figure 2 illustrates a circuit diagram of a rectifier according to an embodiment.

DETAILED DESCRIPTION OF THE INVENTION

[0010] The application of the invention is not limited to any specific system, but it can be used in connection with various electric systems. Moreover, the use of the invention is not limited to systems employing any specific fundamental frequency or any specific voltage level.

[0011] Figure 1 shows an example of a switching branch for a three-level rectifier according to an embodiment. The figure shows only components necessary for understanding the invention. It should be noted that the switching branch configuration could differ from the one shown in Figure 1 without deviating from the basic idea of the invention. The switching branch comprises a first diode D1 and a second diode D2 connected in series between a positive DC output pole U_{dc+} and an AC input pole AC of the switching branch. The switching branch further comprises a third diode D3 and a fourth diode D4 connected in series between the AC input pole AC of the switching branch and a negative DC output pole U_{dc-} . In addition, the switching branch comprises a first controllable switch S1 connected between a neutral DC output pole NP and a connection point between the first and the second diode, and a second controllable switch S2 connected between the neutral DC output pole NP and a connection point between the third and the fourth diode. The switches S1, S2 can be semiconductor switches such as IGBT (Insulated Gate Bipolar Transistor) or FET (Field-Effect Transistor) or any corresponding controllable switches. The figure further shows a control arrangement 10 via which the switches S1, S2 can be controlled. The normal operation of the rectifier includes pulse width modulation (PWM) of the rectifier input voltage by the switches S1, S2 according to a certain modulation method. This may be a vector modulation or a hysteresis modulation method, for example. The invention is not, however, limited to any specific modulation method. The modulation control can involve one or more additional control components (not shown). The exemplary switching branch of Figure 1 can further comprise a fifth diode D5 connected in parallel with the first switch S1 and a sixth diode D6 connected in parallel with the second switch S2. These fifth and sixth diodes are entirely optional and may be omitted in some configurations. The switching branch configuration can also include an AC filter (not shown in Figure 1), which may be e.g. of L-type or LCL-type, that is connected between the AC input pole and a corresponding pole of a supplying AC voltage source.

[0012] According to an embodiment, each switch of the switching branch is set into a conducting state during the time when the switch is not modulating the input voltage of the switching branch. This can be carried out by controlling the first switch S1 of the switching

branch to be in a conductive state during a reverse blocking state of the first diode D1 and the second diode D2, and controlling the second switch S2 of the switching branch to be in a conductive state during a reverse blocking state of the third diode D3 and the fourth diode D4. The reverse blocking state of both the first diode D1 and the second diode D2 occurs when the AC input pole AC of the switching branch is connected to the negative DC output pole Udc- potential, and can be determined e.g. on the basis of the direction of the current through the AC input pole AC. In a similar manner, the reverse blocking state of both the third diode D3 and the fourth diode D4 occurs when the AC input pole AC of the switching branch is connected to the positive DC output pole Udc+ potential, and can be determined e.g. on the basis of the direction of the current through the AC input pole AC.

[0013] The AC input pole of the switching branch can be connected to the neutral DC output pole NP potential by controlling the appropriate active switch according to the current polarity. Thus, the other switch which is not carrying the branch current can remain in the conducting state without any effect on the AC input voltage or current. This means that the switch, which is used for balancing the voltages across the diodes in the reverse blocking state, can stay in the conductive state continuously as long as the diodes to be balanced remain in the reverse blocking state. According to an embodiment, the first switch S1 of the switching branch is controlled to be in the conductive state for each entire period of the reverse blocking state of the first diode D1 and the second diode D2, and the second switch S2 of the switching branch is controlled to be in the conductive state for each entire period of the reverse blocking state of the third diode D3 and the fourth diode D4. In other words, according to this embodiment, the first switch S1 of the switching branch is set to be in the conductive state whenever both the first diode D1 and the second diode D2 are in the reverse blocking state, and the second switch S2 of the switching branch is set to be in the conductive state whenever both the third diode D3 and the fourth diode D4 are in the reverse blocking state.

[0014] According to an embodiment, a three-phase three-level rectifier can be implemented by connecting together three switching branches as described above. Figure 2 illustrates an exemplary circuit diagram of a rectifier according to an embodiment comprising three switching branches corresponding to that of Figure 1. The three switching branches have been connected together by connecting the positive DC output poles Udc+ of each switching branch together, the negative DC output poles Udc- of each switching branch together, and the neutral DC output poles NP of each switching branch together. The figure shows only components necessary for understanding the invention. It should be noted that the rectifier circuit configuration could differ from the one shown in Figure 2 without deviating from the basic idea of the invention. The exemplary three-phase rectifier thus comprises three switching branches with AC input poles AC1, AC2 and AC3, respectively, for connecting the rectifier to the phases of a three phase AC supply (not shown). The rectifier configuration can also include an AC-filter, which may be e.g. of L-type or LCL-type, that is connected between the rectifier input poles and the corresponding poles of the supplying AC-voltage source. This filter is not shown in Figure 2. Each switching branch comprises a first diode D11, D12, D13 and a second diode D21, D22, D23 connected in series between a positive DC output pole Udc+ of the rectifier and an AC input pole of the switching branch AC1, AC2, AC3. Each switching branch further

comprises a third diode D31, D32, D33 and a fourth diode D41, D42, D43 connected in series between the AC input pole of the switching branch AC1, AC2, AC3 and a negative DC output pole Udc- of the rectifier. In addition, each switching branch comprises a first controllable switch S11, S12, S13 connected between a neutral DC output pole NP of the rectifier and a connection point between the first and the second diode, and a second controllable switch S21, S22, S23 connected between the neutral DC output pole NP of the rectifier and a connection point between the third and the fourth diode. The switches S11, S12, S13, S21, S22, S23 can be semiconductor switches such as IGBT (Insulated Gate Bipolar Transistor) or FET (Field-Effect Transistor) or any corresponding controllable switches. The figure further shows a control arrangement 10 via which the switches can be controlled. The normal operation of the rectifier includes pulse width modulation (PWM) of the rectifier input voltage by the switches S11, S12, S13, S21, S22, S23 according to a certain modulation method. This may be a vector modulation or a hysteresis modulation method, for example. The invention is not, however, limited to any specific modulation method. The modulation control can involve one or more additional control components (not shown) possibly included in the rectifier. Each switching branch of the exemplary rectifier of Figure 2 can further comprise a fifth diode D51, D52, D53 connected in parallel with the first switch S11, S12, S13 of each switching branch, and a sixth diode D61, D62, D63 connected in parallel with the second switch S21, S22, S23 of each switching branch. These fifth and sixth diodes are entirely optional and may be omitted in some configurations. The DC intermediate circuit of the exemplary rectifier of Figure 2 can comprise capacitors C1 and C2 as shown. The structure of the intermediate circuit could also be different, depending on the circuit configuration used. The first switch S11, S12, S13 and the second switch S21, S22, S23 of each switching branch are preferably controlled in a manner similar to that described above in connection with the switching branch of Figure 1.

[0015] The control of the switches S1, S11, S12, S13, S2, S21, S22, S23 according to the various embodiments described above can be performed by or via the control arrangement 10 which can also perform the normal modulation control of the switches. It is also possible to use additional or separate logical or physical units (not shown) for performing the control functionality of the invention. The functionality of the invention could, for example, be implemented using a separate logic arrangement which could be independent of the normal modulation control of the switches, for example.

[0016] The control arrangement 10 and/or a separate logic arrangement controlling the switches S1, S11, S12, S13, S2, S21, S22, S23 according to any one of the above embodiments, or a combination thereof, can be implemented as one unit or as two or more separate units that are configured to implement the functionality of the various embodiments. Here the term 'unit' refers generally to a physical or logical entity, such as a physical device or a part thereof or a software routine. The control arrangement 10 according to any one of the embodiments may be implemented at least partly by means of one or more computers or corresponding digital signal processing (DSP) equipment provided with suitable software, for example. Such a computer or digital signal processing equipment preferably comprises at least a working memory (RAM) providing storage area for arithmetical operations and a central processing unit (CPU), such as a general-purpose digital signal processor. The CPU may

comprise a set of registers, an arithmetic logic unit, and a CPU control unit. The CPU control unit is controlled by a sequence of program instructions transferred to the CPU from the RAM. The CPU control unit may contain a number of microinstructions for basic operations. The implementation of microinstructions may vary depending on the CPU design. The program instructions may be coded by a programming language, which may be a high-level programming language, such as C, Java, etc., or a low-level programming language, such as a machine language, or an assembler. The computer may also have an operating system which may provide system services to a computer program written with the program instructions. The computer or other apparatus implementing the invention, or a part thereof, may further comprise suitable input means for receiving e.g. measurement and/or control data, and output means for outputting e.g. control data. It is also possible to use a specific integrated circuit or circuits, or discrete electric components and devices for implementing the functionality according to any one of the embodiments.

[0017] The invention can be implemented in existing system elements or by using separate dedicated elements or devices in a centralized or distributed manner. Present rectifier switching branches or rectifiers, for example, can comprise processors and memory that can be utilized in the functions according to embodiments of the invention. Thus, all modifications and configurations required for implementing an embodiment of the invention e.g. in existing rectifier switching branches or rectifiers may be performed as software routines, which may be implemented as added or updated software routines. If at least part of the functionality of the invention is implemented by software, such software can be provided as a computer program product comprising computer program code which, when run on a computer, causes the computer or a corresponding arrangement to perform the functionality according to the invention as described above. Such a computer program code may be stored or generally embodied on a computer readable medium, such as a suitable memory, e.g. a flash memory or an optical memory, from which it is loadable to the unit or units executing the program code. In addition, such a computer program code implementing the invention may be loaded to the unit or units executing the computer program code via a suitable data network, for example, and it may replace or update a possibly existing program code.

[0018] It is obvious to a person skilled in the art that as technology advances, the basic idea of the invention can be implemented in a variety of ways. Consequently, the invention and its embodiments are not restricted to the above examples, but can vary within the scope of the claims.

REFERENCES CITED IN THE DESCRIPTION

This list of references cited by the applicant is for the reader's convenience only. It does not form part of the European patent document. Even though great care has been taken in compiling the references, errors or omissions cannot be excluded and the EPO disclaims all liability in this regard.

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**Omskiftningsgren til tre niveau-ensretter og fremgangsmåde til styring
af omskiftningsgren til tre niveau-ensretter**

Patentkrav:

1. Omskiftningsgren til en tre niveau-ensretter, hvilken omskiftningsgren omfatter:
 - en første diode (D1; D11, D12, D13) og en anden diode (D2; D21, D22, D23), der er forbundet i serie mellem en AC-indgangspol (AC; AC1, AC2, AC3) i omskiftningsgrenen og en positiv DC-udgangspol (Udc+),
 - en tredje diode (D3; D31, D32, D33) og en fjerde diode (D4; D41, D42, D43), der er forbundet i serie mellem AC-indgangspolen (AC; AC1, AC2, AC3) i omskiftningsgrenen og en negativ DC-udgangspol (Udc-),
 - en første styrbar kontakt (S1, S11, S12, S13), der er forbundet mellem en neutral DC-udgangspol (NP) og et forbindelsespunkt mellem den første og den anden diode, og
 - en anden styrbar kontakt (S2, S21, S22, S23), der er forbundet mellem den neutrale DC-udgangspol (NP) og et forbindelsespunkt mellem den tredje og den fjerde diode,**kendetegnet ved, at** omskiftningsgrenen omfatter en styreindretning (10), der er konfigureret til:
 - at styre den første styrbare kontakt (S1; S11, S12, S13) til at være i en ledende tilstand under en omvendt blokerende tilstand af den første diode (D1; D11, D12, D13) og den anden diode (D2; D21, D22, D23), hvor styreindretningen (10) er konfigureret til at styre den første kontakt til at være i den ledende tilstand for hver hele periode af den omvendt blokerende tilstand af den første diode (D1; D11, D12, D13) og den anden diode (D2; D21, D22, D23), og
 - at styre den anden styrbare kontakt (S2; S21, S22, S23) til at være i en ledende tilstand under en omvendt blokerende tilstand af den tredje diode (D3; D31, D32, D33) og den fjerde diode (D4; D41, D42, D43), hvor styreindretningen (10) er konfigureret til at styre den anden kontakt til at være i den ledende tilstand for hver hele periode af den omvendt blokerende tilstand af den tredje diode (D3; D31, D32, D33) og den fjerde diode (D4; D41, D42, D43).

2. Omskiftningsgren ifølge krav 1, **kendetegnet ved, at** omskiftningsgrenen omfatter en femte diode (D5; D51, D52, D53), der er forbundet parallelt med den første kontakt (S1; S11, S12, S13), og en sjette diode (D6; D61, D62, D63), der er forbundet parallelt med den anden kontakt (S2; S21, S22, S23).
3. Omskiftningsgren ifølge krav 1 eller 2, **kendetegnet ved, at** de styrbare kontakter (S1, S11, S12, S13, S2, S21, S22, S23) er halvlederkontakter.
4. Tre fase-, tre niveau-ensretter omfattende tre omskiftningsgrene ifølge et hvilket som helst af kravene 1 til 3.
5. Fremgangsmåde til styring af en omskiftningsgren til en tre niveau-ensretter, hvilken omskiftningsgren omfatter en første diode (D1; D11, D12, D13) og en anden diode (D2; D21, D22, D23), der er forbundet i serie mellem en AC-indgangspol (AC; AC1, AC2, AC3) i omskiftningsgrenen og en positiv DC-udgangspol (Udc+), en tredje diode (D3; D31, D32, D33) og en fjerde diode (D4; D41, D42, D43), der er forbundet i serie mellem AC-indgangspolen (AC; AC1, AC2, AC3) i omskiftningsgrenen og en negativ DC-udgangspol (Udc-), en første styrbar kontakt (S1, S11, S12, S13), der er forbundet mellem en neutral DC-udgangspol (NP) og et forbindelsespunkt mellem den første og den anden diode, og en anden styrbar kontakt (S2, S21, S22, S23), der er forbundet mellem den neutrale DC-udgangspol (NP) og et forbindelsespunkt mellem den tredje og den fjerde diode,

kendetegnet ved, at fremgangsmåden omfatter:

at styre den første styrbare kontakt (S1; S11, S12, S13) til at være i en ledende tilstand under en omvendt blokerende tilstand af den første diode (D1; D11, D12, D13) og den anden diode (D2; D21, D22, D23), hvor den første kontakt (S1; S11, S12, S13) styres til at være i den ledende tilstand for hver hele periode af den omvendt blokerende tilstand af den første diode (D1; D11, D12, D13) og den anden diode (D2; D21, D22, D23), og

at styre den anden styrbare kontakt (S2; S21, S22, S23) til at være i en ledende tilstand under en omvendt blokerende tilstand af den tredje diode (D3; D31, D32, D33) og den fjerde diode (D4; D41, D42, D43), hvor den anden kontakt (S2; S21, S22, S23) styres til at være i den ledende tilstand for hver hele periode af den omvendt blokerende tilstand af den tredje diode (D3; D31, D32, D33) og den fjerde diode (D4; D41, D42, D43).

6. Fremgangsmåde ifølge krav 5, **kendetegnet ved, at** omskiftningsgrenen omfatter en femte diode (D5; D51, D52, D53), der er forbundet parallelt med den første kontakt (S1; S11, S12, S13), og en sjette diode (D6; D61, D62, D63), der er forbundet parallelt med den anden kontakt (S2; S21, S22, S23).

7. Fremgangsmåde ifølge krav 5 eller 6, **kendetegnet ved, at** de styrbare kontakter (S1, S11, S12, S13, S2, S21, S22, S23) er halvledekontakter.

DRAWINGS

Fig. 1

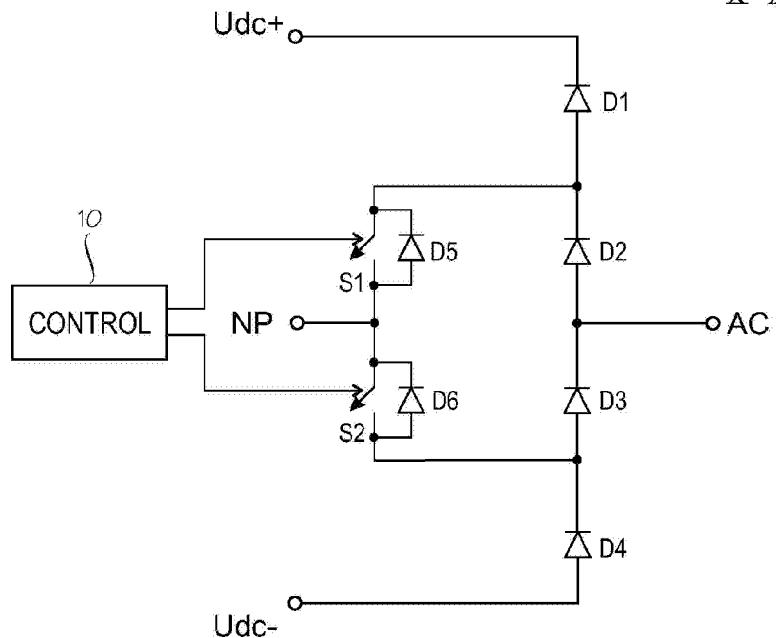


Fig. 2

